# ADVANCED SEMICONDUCTOR ENGINEERING INC Form SD May 31, 2017

UNITED STATES SECURITIES AND EXCHANGE COMMISSION Washington, D.C. 20549

FORM SD

Specialized Disclosure Report

#### ADVANCED SEMICONDUCTOR ENGINEERING, INC.

(Exact name of the registrant as specified in its charter)

Taiwan, Republic of China 001-16125

(State or other jurisdiction of Incorporation or organization) (Commission (IRS Employer Identification No.)

26 Chin Third Road

Nantze Export Processing Zone

Nantze, Kaohsiung, Taiwan Republic of China (Address of principal executive offices)

(Zip code)

Joseph Tung

886-2-8780-5489

(Name and telephone number, including area code, of the person to contact in connection with this report.)

Check the appropriate box to indicate the rule pursuant to which this form is being filed, and provide the period to which the information in this form applies:

Rule 13p-1 under the Securities Exchange Act (17 CFR 240.13p-1) for the reporting period from January 1 to December 31, 2016.

#### Section 1 — Conflict Minerals Disclosure

Item 1.01 and 1.02 Conflict Minerals Disclosure and Report, Exhibit

#### **Conflict Minerals Disclosure**

Our Form SD and our Conflict Minerals Report for the year ended December 31, 2016 filed as Exhibit 1.01 to this Form SD are available at http://www.aseglobal.com/en/Csr/SupplyChainDevelopment.asp

#### Section 2 - Exhibits

#### **Item 2.01 Exhibits**

Exhibit 1.01 – Conflict Minerals Report for the reporting period January 1, 2016 to December 31, 2016

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#### **SIGNATURE**

Pursuant to the requirement of the Securities Exchange Act of 1934, the registrant has duly caused this report to be signed on its behalf by the duly authorized undersigned.

**Advanced Semiconductor Engineering, Inc.** 

By:/s/ Jason C.S. Chang Jason C.S. Chang Chief Executive Officer

Date: May 31,2017

#### **EXHIBIT INDEX**

## Exhibit **Description**

# Number

1.01 Conflict Minerals Report for the reporting period January 1, 2016 to December 31, 2016